

20 69.8 22%

9.6 140% 6.8 24.6%

4.6 27.4% 20 5.7 8%

48% 21Q1 20.4

31.5% 4.0 252% 21Q1

IGBT **SiC** 0.6

20 44.8% MOSFET 20

75% IGBT 1

6 1200V SiC 650V SiC

8 0.18μ m BCD G3 600V SOI 8 0.11μ m 6

8 5G

21-23 1.07 1.36 1.70 21-22

21-23

1.07 1.36 1.70

21-

	2019A	2020A	2021E	2022E	2023E
:	1,931	6,866	11,076	11,695	12,704
	1,491	1,795	2,138	2,589	3,138
	52	52	61	74	90
	1,055	1,269	1,432	1,730	2,083
	564	932	935	938	942

	2019A	2020A	2021E	2022E	2023E
:	5,743	6,977	8,308	10,061	12,194
	4,431	5,061	5,711	6,898	8,305
	66	69	82	99	120
	112	106	125	146	171
	859	936	1,038	1,192	1,427

